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muRata

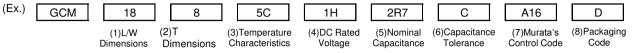
CHIP MONOLITHIC CERAMIC CAPACITOR FOR AUTOMOTIVE GCM1885C1H2R7CA16_ (0603, C0G, 2.7pF, 50Vdc)

_: packaging code

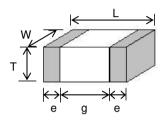
1.Scope

This product specification is applied to Chip Monolithic Ceramic Capacitor used for Automotive Electronic equipment.

2.MURATA Part NO. System



3. Type & Dimensions



				(Unit:mm)
(1)-1 L	(1)-2 W	(2) T	e	g
1.6±0.1	0.8±0.1	0.8±0.1	0.2 to 0.5	0.5 min.

4.Rated value

. ,	Characteristics ode):C0G(EIA)	(4) DC Rated	(5) Nominal	(6) Canacitance	Specifications and Test Methods
Temp. coeff or Cap. Change	Temp. Range (Ref.Temp.)	Voltage	Capacitance	Tolerance	(Operationg Temp. Range)
0±30 ppm/°C	25 to 125 °C (25 °C)	50 Vdc	2.7 pF	±0.25 pF	-55 to 125 °C

5.Package

mark	(8) Packaging	Packaging Unit
D	∳180mm Reel PAPER W8P4	4000 pcs./Reel
J	∳330mm Reel PAPER W8P4	10000 pcs./Reel

Product specifications in this catalog are as of Dec.20,2012,and are subject to change or obsolescence without notice. Please consult the approval sheet before ordering. Please read rating and !Cautions first.

Reference Sheet



			Specif	ication.				
١o			Temperature Compensating Type	High Dielectric Type		A	AEC-Q200 Test Metho	bd
1	Pre-and Post-S Electrical Test	Stress			-			
2	High Temperature Exposure (Storage)		The measured and observed characteristics should satisfy the		Set the capacitor for 1000 ± 12 hours at $150\pm3^{\circ}$ C. Set for 24 ± 2 hours at room temperature, then measure.			
		Appearance	specifications in the following table. No marking defects			at room tempe	rature, men measure.	
		Capacitance	Within ±2.5% or ±0.25pF	R7/L8/R9: Within ±10.0%	1			
		Change	(Whichever is larger)					
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 W.V.: 25Vmin.: 0.03 max.	+			
		Q/D.F.		W.V.: 16V/10V : 0.05 max.				
			30pFmax.: Q ≧400+20C C: Nominal Capacitance(pF)	R9 : 0.075max.				
		I.R.	More than 10,000MΩ or 500Ω •F		+			
			(Whichever is smaller) R9 : More than 150Ω •F					
3	Temperature C	veling			The share a second			
,	remperature c	yonng	The measured and observed charact	tenstics should satisfy the			porting jig in the same	
			specifications in the following table.		4		 Perform cycle test a 	•
		Appearance	No marking defects	I	+		e following table. Set f	tor 24±2 hours at
		Capacitance	Within ±2.5% or ±0.25pF	R7/L8/R9: Within ±10.0%	room temper	ature, then me	easure	
		Change	(Whichever is larger)		↓	1	-	
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 W.V.: 25Vmin.: 0.03 max.	Step	Time(min)		cles
			30pFmax.: Q ≧400+20C	W.V.: 16V/10V : 0.05 max.			1000 (for △ C/R7)	300 (for 5G/L8/R9)
			C: Nominal Capacitance(pF)	R9 : 0.05max.		15±3	-55°C+0/-3	-55°C+0/-3
					2	1	Room	Room
		I.R.	More than 10,000MΩ or 500Ω •F	1	3	15±3	125°C+3/-0	150°C+3/-0
			(Whichever is smaller)		4	1	Room	Room
						irs at room ten initial measure	•	
4	Destructive Phisical Analys	is	No defects or abnormalities			initial measure	•	
			No defects or abnormalities The measured and observed charact	teristics should satisfy the	Perform the Per EIA-469	initial measure	•	y (80 to 98%)
	Phisical Analys			teristics should satisfy the	Perform the Per EIA-469 Apply the 24	initial measure	ement.	y (80 to 98%)
	Phisical Analys		The measured and observed charac	teristics should satisfy the	Perform the Per EIA-469 Apply the 24 treatment sh	initial measure -hour heat (25 own below, 10	to 65°C) and humidity	
	Phisical Analys	tance Appearance	The measured and observed charac specifications in the following table.	teristics should satisfy the R7/L8/R9: Within ±12.5%	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2	initial measure -hour heat (25 own below, 10	to 65°C) and humidity consecutive times. m temperature, then m	neasure. Humidity
	Phisical Analys	tance Appearance Capacitance	The measured and observed charac specifications in the following table. No marking defects Within ±3.0% or ±0.30pF	-	Perform the Per EIA-469 Apply the 24 treatment sh	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
	Phisical Analys	tance Appearance	The measured and observed charac specifications in the following table. No marking defects	-	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70	initial measure - -hour heat (25 own below, 10 2 hours at roor	to 65°C) and humidity consecutive times. m temperature, then m	neasure. Humidity
	Phisical Analys	tance Appearance Capacitance Change	The measured and observed charact specifications in the following table. No marking defects Within ±3.0% or ±0.30pF (Whichever is larger) 30pFmin. : Q≧350	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24 ± 2 Temperature (°C) 70 65	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
4	Phisical Analys	tance Appearance Capacitance Change	The measured and observed charact specifications in the following table. No marking defects Within ±3.0% or ±0.30pF (Whichever is larger) 30pFmin. : Q≧350 10pF and over, 30pF and below:	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 55	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
	Phisical Analys	tance Appearance Capacitance Change	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 + 5C/2$	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 55 50 45	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
	Phisical Analys	tance Appearance Capacitance Change	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 + 5C/2$ 10 pFmax.: Q $\geq 200 + 10$ C	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 55 50 45 40 35	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
	Phisical Analys	Appearance Capacitance Change Q/D.F.	The measured and observed charac specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10C$ C: Nominal Capacitance(pF)	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 55 50 45 50 45 35 30	initial measure - -hour heat (25 own below, 10 2 hours at roor Humidity	to 65°C) and humidity to consecutive times. temperature, then m Humidity 80-98% Humidity	neasure. Humidity 80~98% Humidity
	Phisical Analys	tance Appearance Capacitance Change	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10C$ C: Nominal Capacitance(pF) More than $10,000$ MQ or 500 Q·F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 50 45 40 30 25 20	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98%	neasure. Humidity 80~98% Humidity
	Phisical Analys	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller)	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24 ±: Temperature (°C) 70 65 50 45 45 45 30 25	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity 0 consecutive times. m temperature, then m Humidity 90~98% 90~98%	neasure. Humidity 80~98% Humidity
	Phisical Analys	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10C$ C: Nominal Capacitance(pF) More than $10,000$ MQ or 500 Q·F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±3 Temperature (°C) 70 65 60 55 50 40 35 30 25 20 15 10 5 10 10 5 10 10 10 10 10 10 10 10 10 10	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98%	neasure. Humidity 80~98% Humidity
	Phisical Analys	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller)	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 55 50 45 40 30 20 55 50 45 40 55 50 45 40 55 50 45 40 55 55 50 45 40 55 55 55 50 45 40 55 55 55 55 55 55 55 55 55 5	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98%	neasure. Humidity 80~98% Humidity
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5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : $\Omega \ge 350$ 10 pF and over, 30 pF and below: $\Omega \ge 275 \pm 5C/2$ 10 pFmax.: $\Omega \ge 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 50 55 50 45 40 45 40 55 50 55 50 15 10 10 10 10 10 10 10 10 10 10	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 10 2 °C 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	Humidity 80~98% 400~98%400~90% 400~90% 400~90%400~400~400~400~400~400~400~400~400~400
5	Phisical Analys	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q ≥ 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller) R9 : More than 150 Ω · F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 65 55 50 45 40 45 40 55 50 45 50 55 55 55 55 55 55 55 55 5	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98%	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 10 10 2°C 10 10 10 10 10 10 10 10 10 10	heasure. Humidity 80~98% 400% 400~98% 400~98% 400~98% 400~98% 400~
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller) R9 : More than 150 Ω · F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 50 45 40 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 1 1 1 1 1 1 2 3 4 5 6 1 ed voltage and d 80 to 85% h	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 10 10 10 10 10 10 10 10 10 10	heasure. Humidity 80~98% Humidity 90~98% 100 - 98% 100 - 98% 100 - 98% 100 - 98
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275+5C/2$ 10 pFmax.: Q $\geq 200+10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller) R9 : More than 150 Ω · F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 10 10 10 10 10 10 10 10 10 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : $Q \ge 350$ 10 pF and over, 30 pF and below: $Q \ge 275 \pm 5C/2$ 10 pFmax.: $Q \ge 200 \pm 10C$ C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275 \pm 5C/2$ 10 pFmax.: Q $\geq 200 \pm 10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or 500 Ω · F (Whichever is smaller) R9 : More than 150 Ω · F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger)	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : $Q \ge 350$ 10 pF and over, 30 pF and below: $Q \ge 275 \pm 5C/2$ 10 pFmax.: $Q \ge 200 \pm 10C$ C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pF and over: $Q \ge 200$	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max. teristics should satisfy the R7/L8/R9: Within ±12.5% R7/L8 W.V.: 25Vmin.: 0.035 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : Q \geq 350 10 pF and over, 30 pF and below: $Q \geq 275+5C/2$ 10 pFmax.: Q $\geq 200+10$ C C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pF and over: Q ≥ 200 30 pF and over: Q $\geq 100+10$ C/3 C: Nominal Capacitance(pF)	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max. teristics should satisfy the R7/L8/R9: Within ±12.5% R7/L8 W.V.: 25Vmin.: 0.035 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$
5	Phisical Analys Moisture Resis	Appearance Capacitance Change Q/D.F. I.R. I.R.	The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pFmin. : $Q \ge 350$ 10 pF and over, 30 pF and below: $Q \ge 275 \pm 5C/2$ 10 pFmax.: $Q \ge 200 \pm 10C$ C: Nominal Capacitance(pF) More than $10,000$ MΩ or $500\Omega \cdot$ F (Whichever is smaller) R9 : More than $150\Omega \cdot$ F The measured and observed charact specifications in the following table. No marking defects Within $\pm 3.0\%$ or ± 0.30 pF (Whichever is larger) 30 pF and over: $Q \ge 200$ 30 pF and below: $Q \ge 100 \pm 10C/3$	R7/L8/R9: Within ±12.5% R7/L8 : W.V.: 25Vmin.: 0.03 max. W.V.: 16V/10V : 0.05 max. R9 : 0.075max. teristics should satisfy the R7/L8/R9: Within ±12.5% R7/L8 W.V.: 25Vmin.: 0.035 max. W.V.: 16V/10V : 0.05 max.	Perform the Per EIA-469 Apply the 24 treatment sh Set for 24±2 Temperature (°C) 70 65 60 05 55 50 45 40 45 30 25 50 45 50 50 55 50 45 50 45 50 45 50 45 50 45 50 45 50 45 50 70 70 70 70 70 70 70 70 70 7	-hour heat (25 own below, 10 2 hours at roor Humidity 90~98% 	to 65°C) and humidity consecutive times. m temperature, then m Humidity 90~98% 90~98% 90~98% 100 100 100 100 100 100 100 10	heasure. Humidity $80 \sim 98\%$ Humidity $90 \sim 98\%$ $10 \sim 90\%$ $10 \sim 90\%$

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	_		Speci	ification.		
٥V	AEC-Q200	200 Test Item Temperature Compensating Type		High Dielectric Type	AEC-Q200 Test Method	
7	Operational Life	9	The measured and observed characteristics should satisfy the		Apply 200% of the rated voltage for 1000±12 hours at 125±3°C(for	
			specifications in the following table	•	Δ C/R7), 150±3°C(for 5G/L8/R9).	
		Appearance	No marking defects		Set for 24 ± 2 hours at room temperature, then measure.	
		Capacitance	Within ±3.0% or ±0.30pF	R7/L8/R9: Within ±12.5%	The charge/discharge current is less than 50mA.	
		Change	(Whichever is larger)		-	
		Q/D.F.	30pFmin. : Q≧350	R7/L8 : W.V.: 25Vmin.: 0.035 max. (GCM155R71H 562-223: 0.05max)	 Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximun 	
			10pF and over, 30pF and below: Q≧275+5C/2	W.V.: 16V/10V : 0.05 max.	operating temperature $\pm 3^{\circ}$ C. Remove and set for 24 ± 2 hours at	
			10pFmax.: Q ≧200+10C	R9 : 0.075max.	room temperature. Perform initial measurement.	
			C: Nominal Capacitance(pF)			
		I.R.	More than 1,000MΩ or 50Ω ·F			
			(Whichever is smaller)			
8	External Visual	<u> </u>	No defects or abnormalities		Visual inspection	
9	Phisical Dimen	sion	Within the specified dimensions		Using calipers	
10	Resistance to	Appearance	No marking defects		Per MIL-STD-202 Method 215	
	Solvents	Capacitance	Within the specified tolerance		Solvent 1 : 1 part (by volume) of isopropyl alcohol	
		Change		1	3 parts (by volume) of mineral spirits	
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 : W.V.: 25Vmin.: 0.025 max.	Solvent 2 : Terpene defluxer	
			30pFmax.: Q ≧400+20C	W.V.: 16V/10V : 0.035 max.	Solvent 3 : 42 parts (by volume) of water	
			C: Nominal Capacitance(pF)	R9 : 0.05max.	1part (by volume) of propylene glycol monomethylether	
					1 part (by volume) of monoethanolomine	
		I.R.	More than 10,000M Ω or 500 $\Omega\cdot F$			
			(Whichever is smaller)			
	Mashariaal	A				
	Mechanical Shock	Appearance Capacitance	No marking defects Within the specified tolerance		Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks).	
	SHOCK	Change			The specified test pulse should be Half-sine and should have a	
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 : W.V.: 25Vmin.: 0.025 max.	duration :0.5ms, peak value:1500g and velocity change: 4.7m/s.	
		G/D.I .	30pFmax.: Q ≧400+20C	W.V.: 16V/10V : 0.035 max.		
			C: Nominal Capacitance(pF)	R9 : 0.05max.		
		I.R.	More than 10,000M Ω or 500 $\Omega\cdot F$			
			(Whichever is smaller)			
			,			
12	Vibration	Appearance	No defects or abnormalities		Solder the capacitor to the test jig (glass epoxy board) in the same	
12	Vibration	Capacitance	No defects or abnormalities Within the specified tolerance		manner and under the same conditions as (19). The capacitor	
12	Vibration	Capacitance Change	Within the specified tolerance		manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total	
12	Vibration	Capacitance	Within the specified tolerance 30pFmin. : Q≧1000	R7/L8 : W.V.: 25Vmin.: 0.025 max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between	
12	Vibration	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C	W.V.: 16V/10V : 0.035 max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from	
12	Vibration	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000		manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in	
12	Vibration	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12	
12	Vibration	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω •F	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in	
12	Vibration	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12	
	Vibration Resistance to	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω •F	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12	
		Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω •F (Whichever is smaller)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).	
	Resistance to	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed character	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).	
	Resistance to	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed character specifications in the following table	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).	
	Resistance to	Capacitance Change Q/D.F. I.R. Appearance Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed chara specifications in the following table No marking defects Within the specified tolerance	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. acteristics should satisfy the	 manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times). Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure. Initial measurement for high dielectric constant type 	
	Resistance to	Capacitance Change Q/D.F. I.R. Appearance Capacitance	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed chara specifications in the following table No marking defects Within the specified tolerance 30pFmin. : Q≧1000	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. acteristics should satisfy the e. R7/L8 : W.V.: 25Vmin.: 0.025 max.	 manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times). Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure. Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set 	
	Resistance to	Capacitance Change Q/D.F. I.R. Appearance Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed chara specifications in the following table No marking defects Within the specified tolerance	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. acteristics should satisfy the	 manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times). Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure. Initial measurement for high dielectric constant type 	
	Resistance to	Appearance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed charaspecifications in the following table No marking defects Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q ≧400+20C C: Nominal Capacitance(pF)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. acteristics should satisfy the s. R7/L8 : W.V.: 25Vmin.: 0.025 max. W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	 manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times). Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure. Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature. 	
	Resistance to	Capacitance Change Q/D.F. I.R. Appearance Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 10,000MΩ or 500Ω • F (Whichever is smaller) The measured and observed chars specifications in the following table No marking defects Within the specified tolerance 30pFmax.: Q≧1000 30pFmax.: Q≧400+20C	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. acteristics should satisfy the s. R7/L8 : W.V.: 25Vmin.: 0.025 max. W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	 manner and under the same conditions as (19). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2000Hz. The frequency range, from 10 to 2000Hz and return to 10Hz, should be traversed in approximately 20 minutes. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times). Immerse the capacitor in a eutectic solder solution at 260±5°C for 10±1 seconds. Set at room temperature for 24±2 hours, then measure. Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10 °C for one hour and then set for 24±2 hours at room temperature. 	

			Spec	ification.					
No			Temperature Compensating Type	High Dielectric Type			AEC-Q200 Tes	st Method	
4	Thermal Sh	nock	The measured and observed charact			Fix the capacitor to the supporting jig in the same manner and under			
		Appearance	specifications in the following table.		-			300 cycles according to	
		Appearance	No marking defects Within ±2.5% or ±0.25pF	R7/L8/R9: Within ±10.0%	_			wing table(Maximum	
		Capacitance		R7/L8/R9. WILIIII ±10.0%			conds). Set for 24±	2 hours at room	
		Change	(Whichever is larger)		temper	ature, then me			
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 : W.V.: 25Vmin.: 0.025 max.*		Step	1	2	
			30pFmax.: Q ≧400+20C	*0.05max:GCM188R71E/1H563 to 104		Temp.(°C)	-55+0/-3	125+3/-0(for∆C/R7)	
			C: Nominal Capacitance(pF)	W.V.: 16V/10V : 0.035 max.				150+3/-0 (for 5G/L8/R9)	
				R9 : 0.05max		Time (min.)	15±3	15±3	
		I.R.	More than 10,000MΩ or 500Ω · F				1 1		
			(Whichever is smaller)		Perform for 24±	n a heat treatn	m temperature.	constant type C for one hour and then set	
5	ESD	Appearance	No marking defects		Per AE	C-Q200-002			
		Capacitance	Within the specified tolerance		1				
		Change							
		Q/D.F.	30pFmin. : Q≧1000	R7/L8 : W.V.: 25Vmin.: 0.025 max.	1				
			30pFmax.: Q ≧400+20C	W.V.: 16V/10V :0.035 max.					
			C: Nominal Capacitance(pF)	R9 : 0.05max.					
		I.R.	More than 10,000M Ω or 500 $\Omega \cdot F$ (Whichever is smaller)						
6	Solderabilit			ered evenly and continuously.	(a) Preheat at 155°C for 4 hours. After preheating, immerse the capacitor in a solution of ethanol(JIS-K-8101) and rosin (JIS-K-				
					eute	ctic solder sol	in weight propotion) ution for 5+0/-0.5 se		
					Afte	r preheating, i	mmerse the capacit		
					prop	ootion). Immers onds at 235±5		solution for 5+0/-0.5	
					prop secc (c) show Afte etha prop	uld be placed i r preheating, in nol(JIS-K-810	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder	8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight	
7	Electrical	Appearance	No defects or abnormalities		prop seco (c) shou Afte etha prop seco	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder	8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight	
	Electrical Chatacteri-	Appearance Capacitance	No defects or abnormalities Within the specified tolerance		prop seco (c) shou Afte etha prop seco Visual i	uld be placed i r preheating, ii anol(JIS-K-810 votion). Immers nds at 260±5°	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5	
					(c) show Afte etha prop seco Visual i The ca	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers nds at 260±5° inspection. pacitance/Q/D	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C.	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the	
	Chatacteri-	Capacitance		R7/L8 : W.V.: 25Vmin.: 0.025 max.	(c) show Afte etha prop seco Visual i The ca	onds at 235±5 r preheating, in nol(JIS-K-810 xotion). Immers nds at 260±5° inspection. pacitance/Q/D ncy and voltag	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measu e shown in the table	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the	
	Chatacteri-	Capacitance Change	Within the specified tolerance	R7/L8 : W.V.: 25Vmin.: 0.025 max. W.V.: 16V/10V : 0.035 max.	(c) show Afte etha prop seco Visual i The ca	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers nds at 260±5° inspection. pacitance/Q/D	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder C. I.F. should be meass e shown in the table Δ C,5G	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the Δ C,5G (more than 1000pF)	
	Chatacteri-	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000		(c) shou Afte etha prop seco Visual i The cal frequer	uld be placed i r preheating, ii anol(JIS-K-810 botion). Immers- inds at 260±5° inspection. pacitance/Q/D incy and voltag	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder C. .F. should be measu e shown in the table ΔC,5G (1000 pF and belo	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the $\Delta C,5G$ (more than 1000pF) $R7,R9,L8(C \le 10 \mu F)$	
	Chatacteri-	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C	W.V.: 16V/10V : 0.035 max.	(c) shou Afte etha prop seco Visual i The cal frequer	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immersinds at 260±5° inspection. pacitance/Q/D ncy and voltage Char.	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measu e shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\frac{\Delta C,5G}{(more than 1000pF)}$ R7,R9,L8(C≦10 μ F) 1±0.1kHz	
	Chatacteri-	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C	W.V.: 16V/10V : 0.035 max.	c) shou (c) shou Afte etha prop seco Visual i The cau frequer	uld be placed i r preheating, ii anol(JIS-K-810 botion). Immers- inds at 260±5° inspection. pacitance/Q/D incy and voltag	°C. into steam aging for mmerse the capacit 1) and rosin (JIS-K- se in eutectic solder C. .F. should be measu e shown in the table ΔC,5G (1000 pF and belo	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the $\Delta C,5G$ (more than 1000pF) $R7,R9,L8(C \le 10 \mu F)$	
	Chatacteri-	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max.	C Shou (C) Shou Afte etha prop seco Visual i The cal frequer	onds at 235±5 uld be placed if r preheating, ii unol(JIS-K-810 potion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measive e shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz 0.5 to 5Vrms	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the a. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms	
	Chatacteri-	Capacitance Change	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C	W.V.: 16V/10V : 0.035 max.	C Shou C Shou Afte etha prop seco Visual i The cau frequer F V The ins exceed	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measure a shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz 0.5 to 5Vrms nce should be measure	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7// 150°C	
	Chatacteri-	Capacitance Change Q/D.F. I.R. 25°C	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 100,000MΩ or 1000Ω • F (Whichever is smaller)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. More than 10,000MΩ or 500Ω+F (Whichever is smaller)	C Shou C Shou Afte etha prop seco Visual i The cau frequer F V The ins exceed	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measure a shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz 0.5 to 5Vrms nce should be measure voltage at 25°C and	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7// 150°C	
	Chatacteri-	Capacitance Change Q/D.F.	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 100,000MΩ or 1000Ω • F	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. More than 10,000MΩ or 500Ω+F	C Shou C Shou Afte etha prop seco Visual i The cau frequer F V The ins exceed	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measure a shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz 0.5 to 5Vrms nce should be measure voltage at 25°C and	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7// 150°C	
	Chatacteri-	Capacitance Change Q/D.F. I.R. 25°C	Within the specified tolerance $30pFmin. : Q \ge 1000$ $30pFmax.: Q \ge 400+20C$ C: Nominal Capacitance(pF)More than 100,000M Ω or 1000 Ω ·F(Whichever is smaller)More than 10,000M Ω or 100 Ω ·F	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. More than 10,000MΩ or 500Ω+F (Whichever is smaller) More than 1,000MΩ or 10Ω+F	C Shou C Shou Afte etha prop seco Visual i The cau frequer F V The ins exceed	uld be placed i r preheating, ii nol(JIS-K-810 potion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. .F. should be measure a shown in the table ΔC,5G (1000 pF and belo 1±0.1MHz 0.5 to 5Vrms nce should be measure voltage at 25°C and	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7// 150°C	
	Chatacteri-	Capacitance Change Q/D.F. I.R. 25°C I.R. 125°C I.R. 150°C	Within the specified tolerance $30pFmin. : Q \ge 1000$ $30pFmax.: Q \ge 400+20C$ C: Nominal Capacitance(pF)More than 100,000M Ω or 1000 Ω ·F(Whichever is smaller)More than 10,000M Ω or 100 Ω ·F(Whichever is smaller)More than 10,000M Ω or 100 Ω ·F(Whichever is smaller)	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. More than 10,000MΩ or 500Ω • F (Whichever is smaller) More than 1,000MΩ or 10Ω • F (Whichever is smaller) More than 1,000MΩ or 1Ω • F	prop secc (c) shou Afte etha prop secc Visual i The cal frequer V The ins exceed (for 5C	uld be placed i r preheating, ii nol(JIS-K-810 botion). Immers inds at 260±5° inspection. pacitance/Q/D ncy and voltage Char. Item requency foltage	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. I.F. should be measive a Shown in the table ΔC,5G (1000 pF and belor 1±0.1MHz 0.5 to 5Vrms Ince should be measive nce should be measive nce should be measive nce should be measive a 25°C and a 2 minutes of charge	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the b. $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7// 150°C	
	Chatacteri-	Capacitance Change Q/D.F. I.R. 25°C I.R. 125°C	Within the specified tolerance 30pFmin. : Q≧1000 30pFmax.: Q≧400+20C C: Nominal Capacitance(pF) More than 100,000MΩ or 1000Ω • F (Whichever is smaller) More than 10,000MΩ or 100Ω • F (Whichever is smaller) More than 10,000MΩ or 100Ω • F (Whichever is smaller) More than 10,000MΩ or 100Ω • F	W.V.: 16V/10V : 0.035 max. R9 : 0.05max. More than 10,000MΩ or 500Ω • F (Whichever is smaller) More than 1,000MΩ or 10Ω • F (Whichever is smaller) More than 1,000MΩ or 1Ω • F	prop secc (c) shou Afte etha prop secc Visual i The cal frequer V The ins exceed (for 5C No failu	uld be placed i r preheating, ii nol(JIS-K-810 botion). Immers inds at 260±5° inspection. pacitance/Q/D rcy and voltage Char. Item requency foltage ulation resista ing the rated v S/L8/R9) within	°C. into steam aging for mmerse the capacit 11) and rosin (JIS-K- se in eutectic solder C. I.F. should be measive a Shown in the table ΔC,5G (1000 pF and belor 1±0.1MHz 0.5 to 5Vrms ince should be measive nce should be measive roltage at 25°C and a 2 minutes of charge	solution for 5+0/-0.5 8 hours±15 minutes. or in a solution of 5902) (25% rosin in weight solution for 120±5 ured at 25°C at the $\Delta C,5G$ (more than 1000pF) R7,R9,L8(C≤10 μ F) 1±0.1kHz 1±0.2Vrms sured with a DC voltage not 125°C (for Δ C/R7)/ 150°C ing.	

			Specification.	
No			Temperature High Dielectric Type	AEC-Q200 Test Method
18	Board Flex Appearance		No marking defects Within ±5.0% or ±0.5pF R7/L8/R9: Within ±10.0%	Solder the capacitor on the test jig (glass epoxy board) shown in Fig1 using a eutectic solder. Then apply a force in the direction shown in Fig 2 for 5±1sec. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.
		Change	(Whichever is larger)	Type ⊐ຜ7້≻∜ b c
		Q/D.F.	30pFmin. : Q≧1000 R7/L8 : W.V.: 25Vmin.: 0.025	
			30pFmax.: Q ≧400+20C W.V.: 16V/10V : 0.035	max. GCM15 0.5 1.5 0.6
			C: Nominal Capacitance(pF) R9 : 0.05max.	GCM18 0.6 2.2 0.9 GCM21 0.8 3.0 1.3
				GCM31 2.0 4.4 1.7
		I.R.	More than 10.000MΩ or 500Ω ·F	GCM32 2.0 4.4 2.6
			(Whichever is smaller)	(in mm)
			image: begin with the second secon	$\begin{array}{c} & & & & \\ & & & & \\ & & & \\ & & & & \\$
19	Terminal	Appearance	No marking defects	Solder the capacitor to the test jig (glass epoxy board) shown in
	Strength		, , , , , , , , , , , , , , , , , , ,	Fig.3 using a eutectic solder. Then apply *18N force in parallel with
		Capacitance	Within specified tolerance	the test jig for 60sec.
		Change		The soldering should be done either with an iron or using the reflow
		Q/D.F.	30pFmin. : Q≧1000 R7/L8 : W.V.: 25Vmin.: 0.025	•
			30pFmax.: Q ≥400+20C W.V.: 16V/10V : 0.035	0
			C: Nominal Capacitance(pF) R9 : 0.05max.	*2N(GCM03/15)
		I.R.	More than 10,000MΩ or 500Ω •F (Whichever is smaller) ラント [*] φ	Type a b c GCM03 0.3 0.9 0.3 GCM15 0.4 1.5 0.5 GCM18 1.0 3.0 1.2 GCM21 1.2 4.0 1.65 GCM32 2.2 5.0 2.9 (in mm) (GCM03/15: 0.8mm) (GCM03/15: 0.8mm) GCM Solder resist Baked electrode or Copper foil
				Fig. 3
20	Beam Load Test		Destruction value should be exceed following one.	Place the capacitor in the beam load fixture as Fig 4.
			< Chip L dimension : 2.5mm max. >	Apply a force. < Chip Length : 2.5mm max. >
			Chip thickness > 0.5mm rank : 20N Chip thickness ≦0.5mm rank : 8N	
				↓
			< Chip L dimension : 3.2mm max. > Chip thickness < 1.25mm rank : 15N Chip thickness ≧ 1.25mm rank : 54.5N	I ron Board
				< Chip Length : 3.2mm min. >
				Fig.4
				Speed supplied the Stress Load : *0.5mm / sec. *GCM03: 0.1mm/sec.



			Speci	fication.			
No	AEC-Q2	00 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method		
21	Capacitance Temperature Characteristics	Capacitance Change	Within the specified tolerance. (Table A)	R7 : Within $\pm 15\%$ (-55°C to +125°C) L8 : Within $\pm 15\%$ (-55°C to +125°C) Within $\pm 15/-40\%$ (+125°C to +150°C) R9 : Within $\pm 15\%$ (-55°C to +150°C)	The capacitance change should be measured after 5 min. at each specified temperature stage. (1)Temperature Compensating Type The temperature coefficient is determind using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step1 through 5 (Δ C: +25°C to +125°C, 5G:+25°C to +150°C other temp. coeffs.:+25°C to +85°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as Table A-1. The capacitance drift is caluculated by dividing the differences between the maximum and minimum measured values in the step		
		Temperature Coefficent Capacitance Drift	Within the specified tolerance. (Table A) Within $\pm 0.2\%$ or ± 0.05 pF (Whichever is larger.)		1,3 and 5 by the cap value in step 3. Step Temperature.(°C) 1 25±2 2 -55±3(for ΔC to R7) 3 25±2 4 125±3(for ΔC/R7), 150±3(for 5G/R9/L8),85±3(for other TC) 5 25±2 (2) High Dielectric Constant Type		
					The ranges of capacitatic constant type The ranges of capacitatic change compared with the above 25° C value over the temperature ranges shown in the table should be within the specified ranges. Initial measurement for high dielectric constant type. Perform a heat treatment at $150+0/-10^{\circ}$ C for one hour and then set for 24 ± 2 hours at room temperature. Perform the initial measurement.		

Table A

	Capacitance Change from 25°C (%)					
	-55		-30		-10	
(ppm/°C)	Max.	Min.	Max.	Min.	Max.	Min.
0± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11
	Nominal Values (ppm/°C) 0± 30	(ppm/°C) <u>Max.</u>	Nominal Values (ppm/°C) <u>-55</u> Max. Min.	Nominal Values (ppm/°C) -55 -3 Max. Min. Max.	Nominal Values (ppm/°C)-55-30Max.Min.Max.Min.	Nominal Values (ppm/°C)-55-30-Max.Min.Max.Min.Max.

Note 1: Nominal values denote the temperature coefficient within a range of 25°C to 125°C(for Δ C)/ 150°C(for 5G)/85°C(for other TC).



1.Tape Carrier Packaging(Packaging Code:D/E/F/L/J/K)

1.1 Minimum Quantity(pcs./reel)

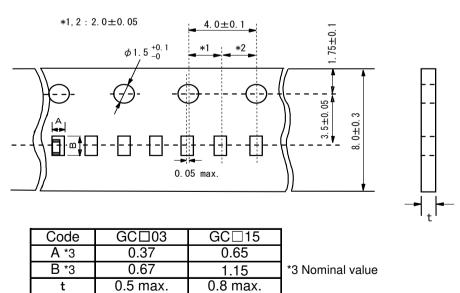
		φ180m	nm reel	φ330n	nm reel
Т	уре	Paper Tape	Plastic Tape	Paper Tape	Plastic Tape
		Code:D/E	Code:L	Code:J/ F	Code:K
GC□03		15000		50000	
GC□15		10000		50000	
GC□18		4000		10000	
	6	4000		10000	
GC□21	9	4000		10000	
	В		3000		10000
	6	4000		10000	
GC□31	9	4000		10000	
GCLST	М		3000		10000
	С		2000		6000
	9	4000		10000	
GC□32	М		3000		10000
GCL32	Ν		2000		8000
	R/D/E		1000		4000
	Μ		1000		5000
GC□43			1000		4000
	E		500		2000
GC□55	М		1000		5000
GC 199	N/R		1000		4000

1.2 Dimensions of Tape

(1)GC□03/15

(in:mm)

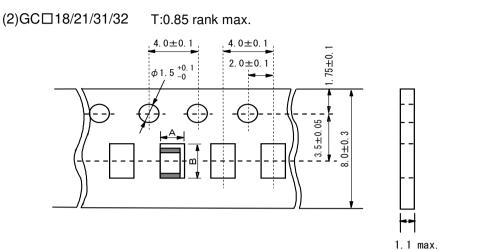
Α



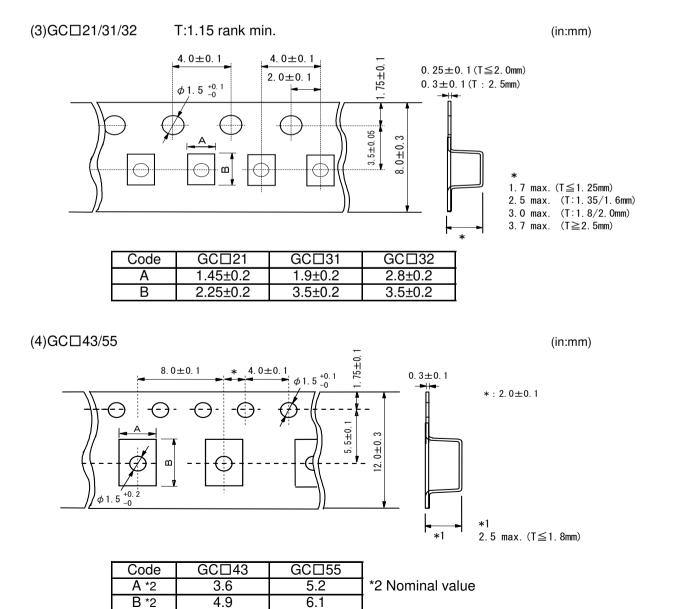
muRata

Package GC□ Type

(in:mm)



Code	GC□18	GC□21	GC□31	GC□32
А	1.05±0.1	1.55±0.15	2.0±0.2	2.8±0.2
В	1.85±0.1	2.3±0.15	3.6±0.2	3.6±0.2



JEMCGP-01894

8

犬態

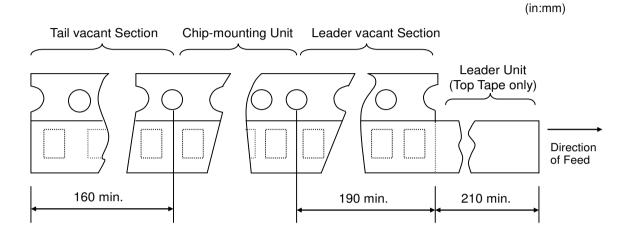
muRata Package GC□ Type Fig.1 Package Chips (in:mm) \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc ()Chip Fig.2 Dimensions of Reel 2.0±0.5 φ21±0.8 φ180+0/-3.0 φ330±2.0 φ50 min. φ13±0.5 W Taping Diagram W_1 Fig.3 GC□32 max. 16.5 max. 10±1.5 GC□43/55 20.5 max. 14±1.5 Top Tape : Thickness 0.06 \mathbb{I} ۵ Feeding Hole :As specified in 1.2. E Õ Hole for Chip : As specified in 1.2. Ø \widehat{O} D 0 Ø Ø Bottom Tape : Thickness 0.05 (Only a bottom tape existence) Base Tape : As specified in 1.2.

単位:

....R...t.

1.3 Tapes for capacitors are wound clockwise shown in Fig.3. (The sprocket holes are to the right as the tape is pulled toward the user.)

1.4 Part of the leader and part of the vacant section are attached as follows.



1.5 Accumulate pitch : 10 of sprocket holes pitch = 40 ± 0.3 mm

1.6 Chip in the tape is enclosed by top tape and bottom tape as shown in Fig.1.

1.7 The top tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.

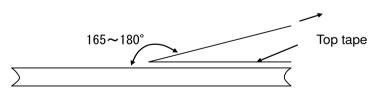
1.8 There are no jointing for top tape and bottom tape.

1.9 There are no fuzz in the cavity.

1.10 Break down force of top tape : 5N min. Break down force of bottom tape : 5N min. (Only a bottom tape existence)

- 図 チップ 詰体状態 is made by resin and appeaser and dimens 単位s shown in Fig 2. There are possibly to change the material and dimension due to some impairment.
 - 1.12 Peeling off force : 0.1N to $0.6N^*$ in the direction as shown below.

* GC□03:0.05N~0.5N



1.13 Label that show the customer parts number, our parts number, our company name, inspection number and quantity, will be put in outside of reel.



Please contact our sales representatives or product engineers before using our products for the applications listed below which require of our products for other applications than specified in this product.
①Aircraft equipment ②Aerospace equipment ③Undersea equipment ④Power plant control equipment ⑤Medical equipment ⑥Transportation equipment(vehicles,trains,ships,etc.) ⑦Traffic signal equipment ⑧Data-processing equipment
①Application of similar complexity and/or requirements to the applications listed in the above

Fail-safe

Be sure to provide an appropriate fail-safe function on your product to prevent a second damage that may be caused by the abnormal function or the failure of our product.

Storage and Operation condition

- 1. The performance of chip monolithic ceramic capacitors may be affected by the storage conditions.
- 1-1. Store capacitors in the following conditions: Temperature of +5°C to +40°C and a Relative Humidity of 20% to 70%.
- (1) Sunlight, dust, rapid temperature changes, corrosive gas atmosphere or high temperature and humidity conditions during storage may affect the solderability and the packaging performance. Please use product within six months of receipt.
- (2) Please confirm solderability before using after six months.Store the capacitors without opening the original bag.Even if the storage period is short, do not exceed the specified atmospheric conditions.
- 1-2. Corrosive gas can react with the termination (external) electrodes or lead wires of capacitors, and result in poor solderability. Do not store the capacitors in an atmosphere consisting of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.).
- 1-3. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes and/or the resin/epoxy coatings, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high huimidity conditions

Rating

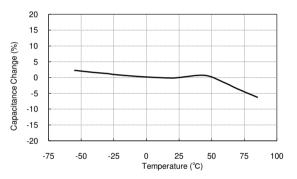
1.Temperature Dependent Characteristics

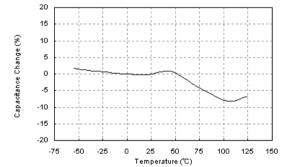
- 1. The electrical characteristics of the capacitor can change with temperature.
- 1-1. For capacitors having larger temperature dependency, the capacitance may change with temperature changes. The following actions are recommended in order to insure suitable capacitance values.
- (1) Select a suitable capacitance for the operating temperature range.
- (2) The capacitance may change within the rated temperature. When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance.

Example: a time constant circuit., please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics.

And check capacitors using your actual appliances at the intended environment and operating conditions.

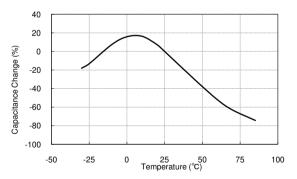
□ Typical temperature characteristics Char.R6 (X5R)





□ Typical temperature characteristics Char.R7 (X7R)

□ Typical temperature characteristics Char.F5 (Y5V)



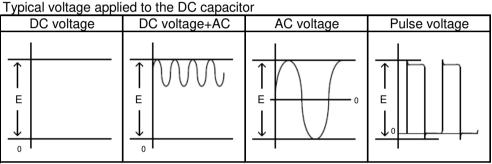
2.Measurement of Capacitance

1. Measure capacitance with the voltage and the frequency specified in the product specifications.

- 1-1. The output voltage of the measuring equipment may decrease when capacitance is high occasionally. Please confirm whether a prescribed measured voltage is impressed to the capacitor.
- 1-2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

3.Applied Voltage

- 1. Do not apply a voltage to the capacitor that exceeds the rated voltage as called-out in the specifications.
- 1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.
- (1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage. When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.
- (2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.



(E : Maximum possible applied voltage.)

1-2. Influence of overvoltage

Overvoltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers .

The time duration until breakdown depends on the applied voltage and the ambient temperature.

4. Applied Voltage and Self-heating Temperature

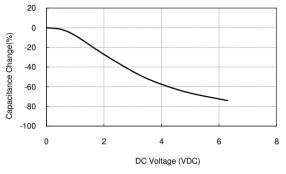
- 1. When the capacitor is used in a high-frequency voltage, pulse voltage, application, be sure to take into account self-heating may be caused by resistant factors of the capacitor.
- 1-1. The load should be contained to the level such that when measuring at atomospheric temperature of 25°C, the product's self-heating remains below 20°C and surface temperature of the capacitor in the actual circuit remains within the maximum operating temperature.

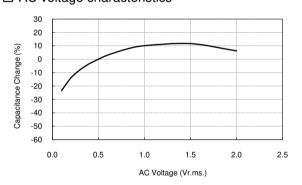


5. DC Voltage and AC Voltage Characteristic

- 1. The capacitance value of a high dielectric constant type capacitor changes depending on the DC voltage applied. Please consider the DC voltage characteristics when a capacitor is selected for use in a DC circuit.
- 1-1. The capacitance of ceramic capacitors may change sharply depending on the applied voltage. (See figure) Please confirm the following in order to secure the capacitance.
- Whether the capacitance change caused by the applied voltage is within the range allowed or not.
- (2) In the DC voltage characteristics, the rate of capacitance change becomes larger as voltage increases.
 Even if the applied voltage is below the rated voltage.
 When a high dielectric constant type capacitor is in a circuit that needs a tight (narrow) capacitance tolerance.
 Example: a time constant circuit., please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics.
 And check capacitors using your actual appliances at the intended environment and operating conditions.

DC voltage characteristics





6. Capacitance Aging

1. The high dielectric constant type capacitors have the characteristic in which the capacitance value decreases with the passage of time.

When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance. Example: a time constant circuit., please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics.

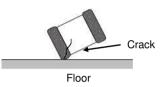
And check capacitors using your actual appliances at the intended environment and operating conditions.



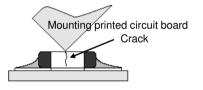


7.Vibration and Shock

- 1. The capacitors mechanical actress (vibration and shock) shall be specified for the use environment. Please confirm the kind of vibration and/or shock, its condition, and any generation of resonance. Please mount the capacitor so as not to generate resonance, and do not allow any impact on the terminals.
- 2. Mechanical shock due to falling may cause damage or a crack in the dielectric material of the capacitor. Do not use a fallen capacitor because the quality and reliability may be deteriorated.



3. When printed circuit boards are piled up or handled, the corners of another printed circuit board should not be allowed to hit the capacitor in order to avoid a crack or other damage to the capacitor.

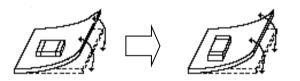


Soldering and Mounting

1.Mounting Position

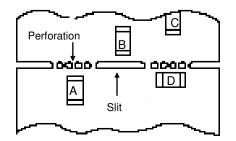
- 1. Confirm the best mounting position and direction that minimizes the stress imposed on the capacitor during flexing or bending the printed circuit board.
- 1-1.Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.

[Component Direction]



Locate chip horizontal to the direction in which stress acts

[Chip Mounting Close to Board Separation Point]



Chip arrangement Worst A-C-(B~D) Best

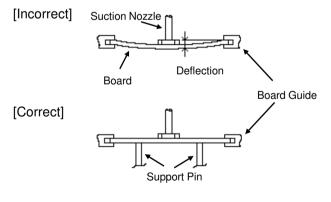


2.Information before mounting

- 1. Do Not re-use capacitors that were removed from the equipment.
- 2. Confirm capacitance characteristics under actual applied voltage.
- 3. Confirm the mechanical stress under actual process and equipment use.
- 4. Confirm the rated capacitance, rated voltage and other electrical characteristics before assembly.
- 5. Prior to use, confirm the Solderability for the capacitors that were in long-term storage.
- 6. Prior to measuring capacitance, carry out a heat treatment for capacitors that were in long-term storage.
- 7. The use of Sn-Zn based solder will deteriorate the reliability of the MLCC. Please contact our sales representative or product engineers on the use of Sn-Zn based solder in advance.

3.Maintenance of the Mounting (pick and place) Machine

- 1. Make sure that the following excessive forces are not applied to the capacitors.
- 1-1. In mounting the capacitors on the printed circuit board, any bending force against them shall be kept to a minimum to prevent them from any bending damage or cracking. Please take into account the following precautions and recommendations for use in your process.
- (1) Adjust the lowest position of the pickup nozzle so as not to bend the printed circuit board.
- (2) Adjust the nozzle pressure within a static load of 1N to 3N during mounting.



2. Dirt particles and dust accumulated between the suction nozzle and the cylinder inner wall prevent the nozzle from moving smoothly. This imposes greater force upon the chip during mounting, causing cracked chips. Also the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.





4-1.Reflow Soldering

- 1. When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB board. Preheating conditions are shown in table 1. It is required to keep the temperature differential between the solder and the components surface (ΔT) as small as possible.
- 2. Solderability of Tin plating termination chips might be deteriorated when a low temperature soldering profile where the peak solder temperature is below the melting point of Tin is used. Please confirm the Solderability of Tin plated termination chips before use.
- 3. When components are immersed in solvent after mounting be sure to maintain the temperature difference (ΔT) between the component and the solvent within the range shown in the table 1.

Table 1

Part Number	Temperature Differential
GC□03/15/18/21/31	ΔT≦190°C
GC□32	ΔT≦130℃

Recommended Conditions

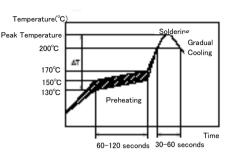
	Pb-Sn	Lead Free Solder	
	Infrared Reflow	Vapor Reflow	Lead Tree Solder
Peak Temperature	230~250°C	230~240°C	240~260°C
Atmosphere	Air	Air	Air or N2
Pb-Sn Solder: Sn-37Pb		Lead Free Solde	er: Sn-3.0Ag-0.5Cu

4. Optimum Solder Amount for Reflow Soldering

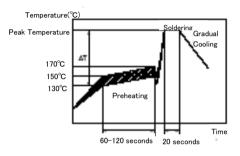
- 4-1. Overly thick application of solder paste results in a excessive solder fillet height. This makes the chip more susceptible to mechanical and thermal stress on the board and may cause the chips to crack.
- 4-2. Too little solder paste results in a lack of adhesive strength on the outer electrode, which may result in chips breaking loose from the PCB.
- 4-3. Make sure the solder has been applied smoothly to the end surface to a height of 0.2mm* min.

[Standard Conditions for Reflow Soldering]

Infrared Reflow



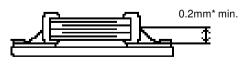




[Allowable Soldering Temperature and Time]



In case of repeated soldering, the accumulated soldering time must be within the range shown above.



* GC□03: 1/3 of Chip Thickness min.

in section

Inverting the PCB Make sure not to impose any abnormal mechanical shocks to the PCB. JEMCGC-2702N 17

4-2.Flow Soldering

- 1. When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage in the components, preheating should be required for both of the components and the PCB board. Preheating conditions are shown in table 2. It is required to keep temperature differential between the solder and the components surface (ΔT) as small as possible.
- 2. Excessively long soldering time or high soldering temperature can result in leaching of the outer electrodes, causing poor adhesion or a reduction in capacitance value due to loss of contact between electrodes and end termination.
- 3. When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and solvent within the range shown in the table 2.
- 4. Do not apply flow soldering to chips not listed in Table 2.

Table 2

Part Number	Temperature Differential
GC□18/21/31	ΔT≦150°C

Recommended Conditions

Pb-Sn Solder	Lead Free Solder
90~110°C	100~120°C
240~250°C	250~260°C
Air	N ₂
	90~110°C 240~250°C

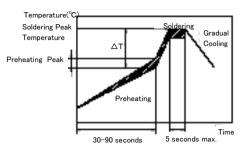
Pb-Sn Solder: Sn-37Pb Lead Free Solder: Sn-3.0Ag-0.5Cu

5. Optimum Solder Amount for Flow Soldering

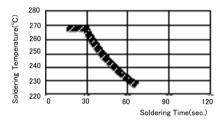
5-1. The top of the solder fillet should be lower than the thickness of components. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition.

Up to Chip Thickness Up to Chip Thickness Adhesive in section

[Standard Conditions for Flow Soldering]







In case of repeated soldering, the accumulated soldering time must be within the range shown above.



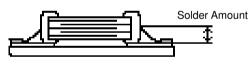
4-3.Correction with a Soldering Iron

- When sudden heat is applied to the components when using a soldering iron, the mechanical strength of the components will decrease because the extreme temperature change can cause deformations inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB board. Preheating conditions, (The "Temperature of the Soldering Iron tip", "Preheating Temperature", "Temperature Differential" between the iron tip and the components and the PCB), should be within the conditions of table 3. It is required to keep the temperature differential between the soldering Iron and the component surfaces (ΔT) as small as possible.
- 2. After soldering, do not allow the component/PCB to rapidly cool down.
- 3. The operating time for the re-working should be as short as possible. When re-working time is too long, it may cause solder leaching, and that will cause a reduction in the adhesive strength of the terminations.

Table 3					
Part Number	Temperature of Soldering Iron tip	Preheating Temperature	Temperature Differential (ΔT)	Atmosphere	
GC□03/15/18/21/31	350°C max.	150°C min.	ΔT≦190°C	Air	
GC□32	280°C max.	150°C min.	ΔT≦130℃	Air	

*Applicable for both Pb-Sn and Lead Free Solder Pb-Sn Solder: Sn-37Pb

- 4. Optimum Solder amount when re-working with a Soldering Iron
- 4-1. In case of sizes smaller than 0603, (GC□03/15/18), the top of the solder fillet should be lower than 2/3's of the thickness of the component or 0.5mm whichever is smaller. In case of 0805 and larger sizes, (GC□21/31/32), the top of the solder fillet should be lower than 2/3's of the thickness of the component. If the solder amount is excessive, the risk of cracking is higher during board bending or under any other stressful condition.



in section

- 4-2. A Soldering iron with a tip of ø3mm or smaller should be used. It is also necessary to keep the soldering iron from touching the components during the re-work.
- 4-3. Solder wire with ø0.5mm or smaller is required for soldering.

4-4.Leaded Component Insertion

 If the PCB is flexed when leaded components (such as transformers and ICs) are being mounted, chips may crack and solder joints may break.
 Before mounting leaded components, support the PCB using backup pins or special jigs to prevent warping.

Lead Free Solder: Sn-3.0Ag-0.5Cu

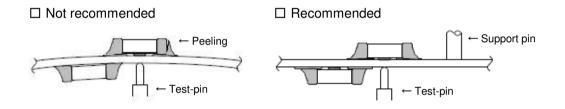


5.Washing

Excessive ultrasonic oscillation during cleaning can cause the PCBs to resonate, resulting in cracked chips or broken solder joints. Take note not to vibrate PCBs.

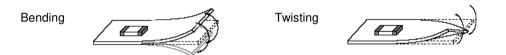
6.Electrical Test on Printed Circuit Board

- 1. Confirm position of the support pin or specific jig, when inspecting the electrical performance of a capacitor after mounting on the printed circuit board.
- 1-1. Avoid bending printed circuit board by the pressure of a test pin, etc. The thrusting force of the test probe can flex the PCB, resulting in cracked chips or open solder joints. Provide support pins on the back side of the PCB to prevent warping or flexing.
- 1-2. Avoid vibration of the board by shock when a test pin contacts a printed circuit board.



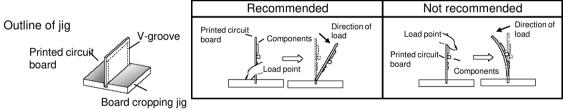
7.Printed Circuit Board Cropping

- 1. After mounting a capacitor on a printed circuit board, do not apply any stress to the capacitor that is caused by bending or twisting the board.
- 1-1. In cropping the board, the stress as shown right may cause the capacitor to crack. Try not to apply this type of stress to a capacitor.



- 2. Check of the cropping method for the printed circuit board in advance.
- 2-1. Printed circuit board cropping shall be carried out by using a jig or an apparatus to prevent the mechanical stress which can occur to the board.
 - (1) Example of a suitable jig

Recommended example: the board should be pushed as close to the near the cropping jig as possible and from the back side of board in order to minimize the compressive stress applied to capacitor. Not recommended example* when the board is pushed at a point far from the cropping jig and from the front side of board as below, the capacitor may form a crack caused by the tensile stress applied to capacitor.

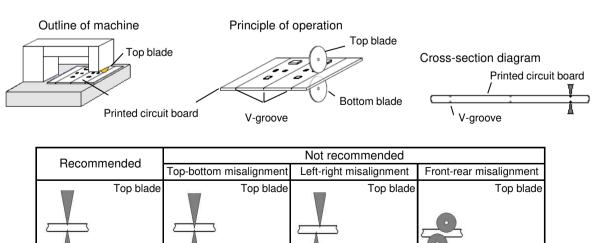


(2) Example of a suitable machine

Bottom blade

An outline of a printed circuit board cropping machine is shown as follows. Along the lines with the V-grooves on printed circuit board, the top and bottom blades are aligned to one another when cropping the board.

The misalignment of the position between top and bottom blades may cause the capacitor to crack.



Bottom blade

Bottom blade

Bottom blade

Others

1. Under Operation of Equipment

- 1-1. Do not touch a capacitor directly with bare hands during operation in order to avoid the danger of a electric shock.
- 1-2. Do not allow the terminals of a capacitor to come in contact with any conductive objects (short-circuit). Do not expose a capacitor to a conductive liquid, inducing any acid or alkali solutions.
- 1-3. Confirm the environment in which the equipment will operation is under the specified conditions. Do not use the equipment under the following environment.
 - (1) Being spattered with water or oil.
 - (2) Being exposed to direct sunlight.
 - (3) Being exposed to Ozone, ultraviolet rays or radiation.
 - (4) Being exposed to toxic gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
 - (5) Any vibrations or mechanical shocks exceeding the specified limits.
 - (6) Moisture condensing environments.

1-4. Use damp proof countermeasures if using under any conditions that can cause condensation.

2. Others

- 2-1. In an Emergency
- If the equipment should generate smoke, fire or smell, immediately turn off or unplug the equipment. If the equipment is not turned off or unplugged, the hazards may be worsened by supplying continuous power.
- (2) In this type of situation, do not allow face and hands to come in contact with the capacitor or burns may be caused by the capacitors high temperature.

2-2. Disposal of waste

When capacitors are disposed, they must be burned or buried by the industrial waste vender with the appropriate licenses.

2-3. Circuit Design

GC Series capacitors in this specification are not safety recognized products.

2-4. Remarks

Failure to follow the cautions may result, worst case, in a short circuit and smoking when the product is used. The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.

Select optimum conditions for operation as they determine the reliability of the product after assembly. The data herein are given in typical values, not guaranteed ratings.



Rating

1.Operating Temperature

- 1. The operating temperature limit depends on the capacitor.
- 1-1.Do not apply temperatures exceeding the upper operating temperature. It is necessary to select a capacitor with a suitable rated temperature which will cover the operating temperature range.

Also it is necessary to consider the temperature distribution in equipment and the seasonal temperature variable factor.

1-2.Consider the self-heating of the capacitor The surface temperature of the capacitor shall be the upper operating temperature or less when including the self-heating factors.

2.Atmosphere surroundings (gaseous and liquid)

- 1. Restriction on the operating environment of capacitors.
- 1-1. The capacitor, when used in the above, unsuitable, operating environments may deteriorate due to the corrosion of the terminations and the penetration of moisture into the capacitor.
- 1-2. The same phenomenon as the above may occur when the electrodes or terminals of the capacitor are subject to moisture condensation.
- 1-3. The deterioration of characteristics and insulation resistance due to the oxidization or corrosion of terminal electrodes may result in breakdown when the capacitor is exposed to corrosive or volatile gases or solvents for long periods of time.

3.Piezo-electric Phenomenon

 When using high dielectric constant type capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated. Moreover, when the mechanical vibration or shock is added to capacitor, noise may occur.

Soldering and Mounting

1.PCB Design

- 1. Notice for Pattern Forms
- 1-1. Unlike leaded components, chip components are susceptible to flexing stresses since they are mounted directly on the substrate.

They are also more sensitive to mechanical and thermal stresses than leaded components. Excess solder fillet height can multiply these stresses and cause chip cracking. When designing substrates, take land patterns and dimensions into consideration to eliminate the possibility of excess solder fillet height.

1-2. It is possible for the chip to crack by the expansion and shrinkage of a metal board. Please contact us if you want to use our ceramic capacitors on a metal board such as Aluminum.

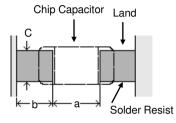
Pattern Forms

	Prohibited	Correct
Placing Close to Chassis	Chassis Solder (ground) Electrode Pattern	Solder Resist
Placing of Chip Components and Leaded Components	Lead Wire	Solder Resist
Placing of Leaded Components after Chip Component	Soldering Iron Lead Wire	Solder Resist
Lateral Mounting		Solder Resist



2. Land Dimensions

2-1. Chip capacitor can be cracked due to the stress of PCB bending / etc if the land area is larger than needed and has an excess amount of solder.Please refer to the land dimensions in table 1 for flow soldering, table 2 for reflow soldering.



Please confirm the suitable land dimension by evaluating of the actual SET / PCB.

Dimensions Part Number	Chip (L×W)	а	b	С
GC□18	1.6×0.8	0.6~1.0	0.8~0.9	0.6~0.8
GC□21	2.0×1.25	1.0~1.2	0.9~1.0	0.8~1.1
GC□31	3.2×1.6	2.2~2.6	1.0~1.1	1.0~1.4

Table 1 Flow Soldering Method

(in mm)

Dimensions Part Number	Chip (L×W)	а	b	С
GC□03	0.6×0.3	0.2~0.3	0.2~0.35	0.2~0.4
GC□15	1.0×0.5	0.3~0.5	0.35~0.45	0.4~0.6
GC□18	1.6×0.8	0.6~0.8	0.6~0.7	0.6~0.8
GC□21	2.0×1.25	1.0~1.2	0.6~0.7	0.8~1.1
GC□31	3.2×1.6	2.2~2.4	0.8~0.9	1.0~1.4
GC□32	3.2×2.5	2.0~2.4	1.0~1.2	1.8~2.3
				(!

Table 2 Reflow Soldering Method

(in mm)